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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Tatsuya Usami

Serial No.: 09/851,313

Group Art Unit: 2823

Filing Date: May 9, 2001

Examiner: Maldonado, Julio J.

For: SEMICONDUCTOR DEVICE AND SEMICONDUCTOR WAFER HAVING
MULTI-LAYERED INSULATION FILM

Commissioner for Patents
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to applicant's duty of disclosure under 37 CFR §1.56, applicant respectfully brings the following documents listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. All of these references were cited by the Examiner in the co-pending Application No. 10/135,393, in an Office Action dated January 4, 2005.


This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicant is aware.

I hereby certify that no item of information contained in the information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing the certification after making reasonable inquiry, no item of information contained in the information disclosure statement was known to any individual designated in § 1.56(c) more than three months prior to the filing of the information disclosure statement.

It is respectfully requested that the listed reference be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Respectfully submitted,

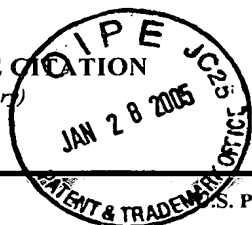

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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)



Docket Number (Optional)

NEC01P069-MSb

Application Number

09/851,313

Applicant(s)

Tatsuya Usami

Filing Date

05/09/01

Group Art Unit

2823

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
		6,624,061 B2	09/23/03	Aoki			
		6,800,928 B1	10/05/04	Lee et al.			

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

		Sun-Young Kim et al., HOSP as a Low Dielectric Material: Comparative Study Against Hydrogen Silsesquioxane, 1999 IEEE, 28-221

EXAMINER	DATE CONSIDERED
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.